

FR2AD THRU FR2MD

Surface Mount Fast Recovery Rectifier

Reverse Voltage – 50 to 1000 V

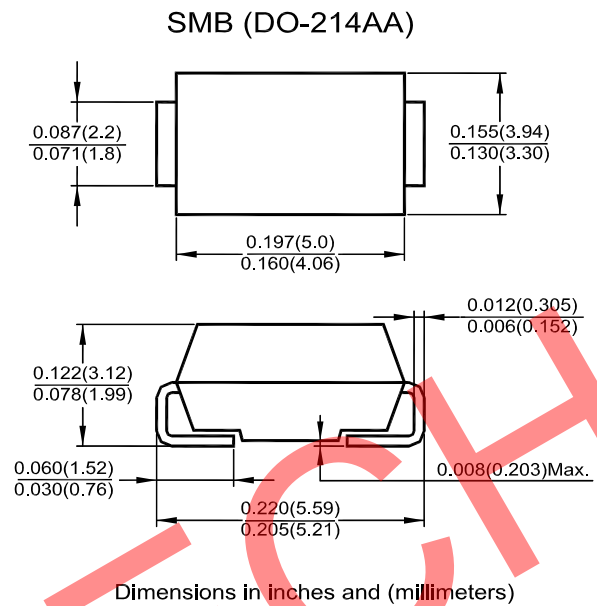
Forward Current – 2 A

Features

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Fast switching for high efficiency
- Low reverse leakage
- High forward surge current capability
- For surface mounted applications

Mechanical Data

- **Case:** Molded plastic, SMB (DO-214AA)
- **Terminals:** Solder plated, solderable per MIL-STD-750, method 2026
- **Polarity:** Color band denotes cathode end



Absolute Maximum Ratings and Characteristics

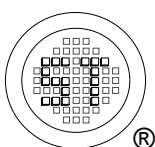
Ratings at 25 °C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	Symbols	FR2AD	FR2BD	FR2DD	FR2GD	FR2JD	FR2KD	FR2MD	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Average Forward Rectified Current at $T_L = 90\text{ }^\circ\text{C}$	$I_{(AV)}$	2							A
Peak Forward Surge Current 8.3 ms Single Half-sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	50							A
Maximum Instantaneous Forward Voltage at 2 A	V_F	1.3							V
Maximum Reverse Current $T_A = 25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage $T_A = 100\text{ }^\circ\text{C}$	I_R	5 50							μA
Maximum Reverse Recovery Time ¹⁾	t_{rr}	150			250		500		ns
Typical Junction Capacitance ²⁾	C_J	50							pF
Typical Thermal Resistance ³⁾	$R_{\theta JA}$	20							$^\circ\text{C/W}$
Operating Junction and Storage Temperature Range	T_j, T_{stg}	- 65 to + 150							$^\circ\text{C}$

¹⁾ Reverse recovery conditions: $I_F = 0.5\text{ A}$, $I_R = 1\text{ A}$, $I_{rr} = 0.25\text{ A}$

²⁾ Measured at 1 MHz and applied reverse voltage of 4 V.

³⁾ P.C.B with 0.2 X 0.2" (5 X 5 mm) copper pad areas.



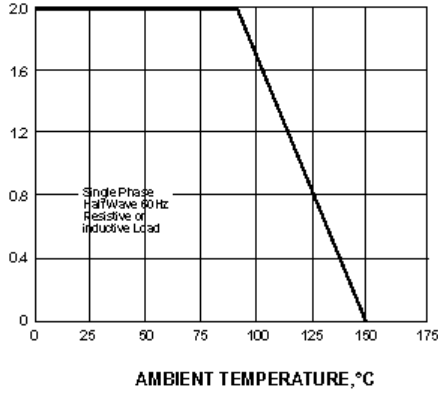
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FR2AD THRU FR2MD

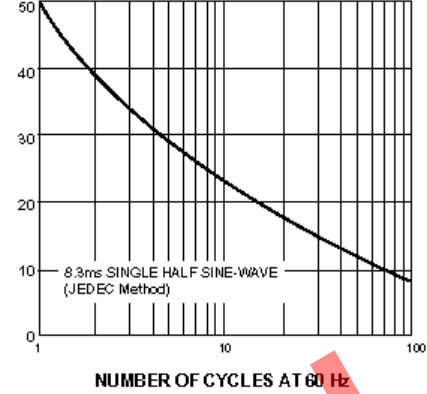
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



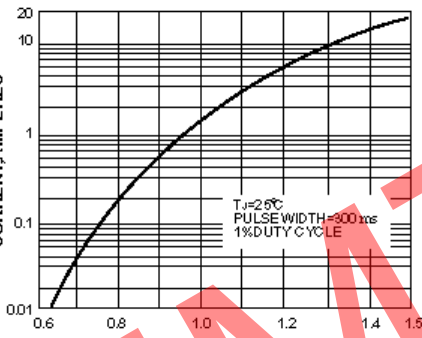
PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



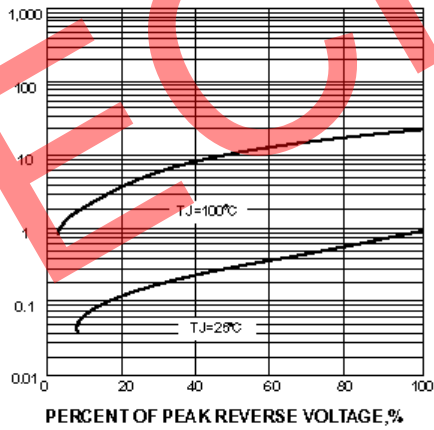
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



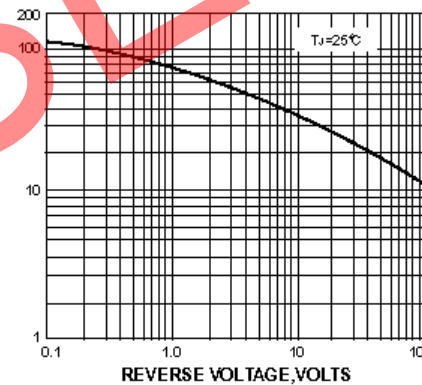
INSTANTANEOUS REVERSE CURRENT, MICROAMPERES

FIG. 4- TYPICAL REVERSE CHARACTERISTICS



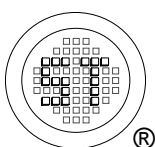
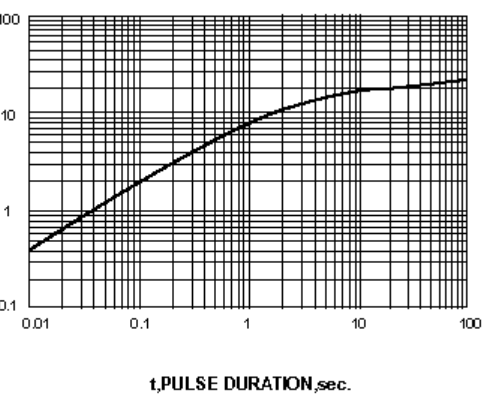
JUNCTION CAPACITANCE, pF

FIG. 5- TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6- TYPICAL TRANSIENT THERMAL IMPEDANCE



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